Preferred Device

General Purpose Transistor

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-323/SC-70 package which is designed for low power surface mount applications.

Features

• Pb–Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector-Base Voltage	V _{CBO}	75	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	Ι _C	600	mAdc

THERMAL CHARACTERISTICS

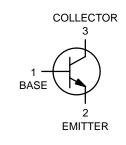
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board $T_A = 25^{\circ}C$	PD	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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MARKING DIAGRAM



P1 = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT2222AWT1	SC-70	3000/Tape & Reel
MMBT2222AWT1G	SC-70 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = $25^{\circ}C$ unless otherwise noted)

Charac	teristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	1)	V _{(BR)CEO}	40	-	Vdc
Collector – Base Breakdown Voltage ($I_C = 10 \ \mu Adc$, $I_E = 0$)		V _{(BR)CBO}	75	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	6.0	-	Vdc
Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc)		I _{BL}	-	20	nAdc
Collector Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc)		ICEX	-	10	nAdc
ON CHARACTERISTICS (Note 1)					
$ \begin{array}{l} \text{DC Current Gain (Note 1)} \\ (I_{C} = 0.1 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 150 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \end{array} $		H _{FE}	35 50 75 100 40	- - 300 -	-
	1)	V _{CE(sat)}		0.3 1.0	Vdc
$\begin{array}{l} \text{Base-Emitter Saturation Voltage (Note 1)} \\ (I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}) \\ (I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}) \end{array}$		V _{BE(sat)}	0.6	1.2 2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product (I _C = 20 mAdc, V _{CE} = 20 Vdc, f = 100 MH	Hz)	f _T	300	-	MHz
Output Capacitance (V_{CB} = 10 Vdc, I_E = 0, f = 1.0 MHz)		C _{obo}	-	8.0	pF
Input Capacitance (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz)		C _{ibo}	-	30	pF
Input Impedance (V_{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kHz	z)	h _{ie}	0.25	1.25	kΩ
Voltage Feedback Ratio (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kHz	z)	h _{re}	-	4.0	X 10 ⁻⁴
Small – Signal Current Gain (V_{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kHz	z)	h _{fe}	75	375	-
Output Admittance $(V_{CE} = 10 \text{ Vdc}, I_C = 10 \text{ mAdc}, f = 1.0 \text{ kHz}$	z)	h _{oe}	25	200	μmhos
Noise Figure (V_{CE} = 10 Vdc, I _C = 100 µAdc, R _S = 1.0 I	κΩ, f = 1.0 kHz)	NF	-	4.0	dB
SWITCHING CHARACTERISTICS					
Delay Time	(V _{CC} = 3.0 Vdc, V _{BE} = -0.5 Vdc,	t _d	-	10	10 ns
Rise Time	$I_{\rm C} = 150 \text{ mAdc}, I_{\rm B1} = 15 \text{ mAdc})$	t _r	-	25	
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_C = 150 \text{ mAdc}, I_{B1} = I_{B2} = 15 \text{ mAdc})$	ts	-	225	ns
Fall Time		t _f	-	60	

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

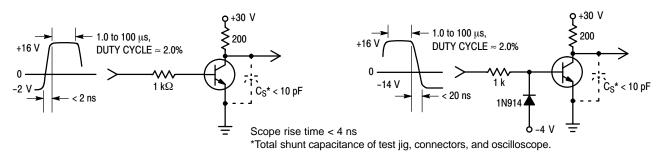
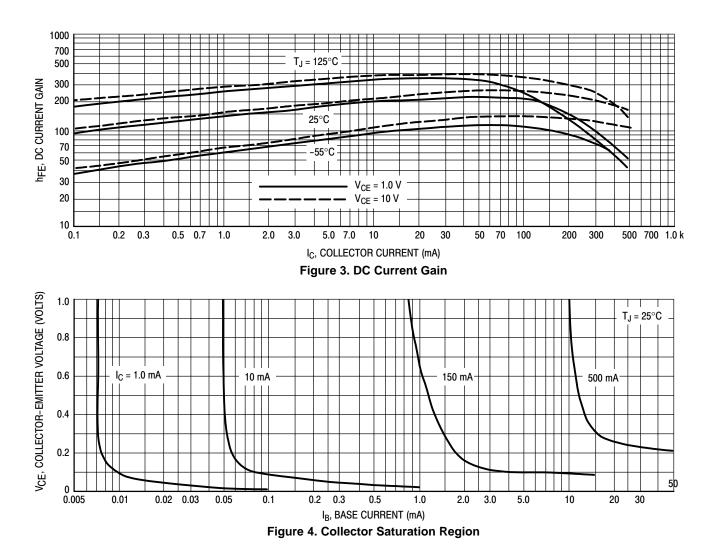




Figure 2. Turn-Off Time



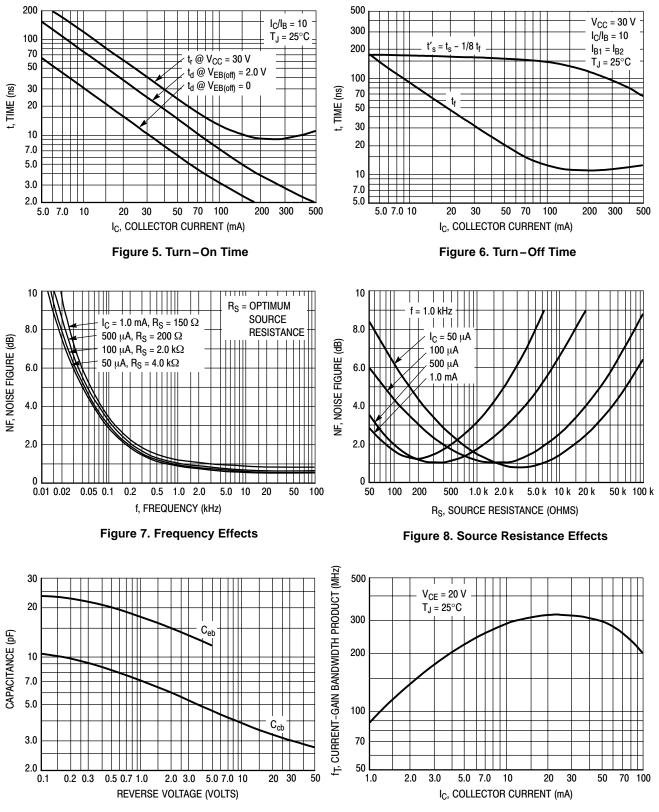


Figure 9. Capacitances

Figure 10. Current–Gain Bandwidth Product

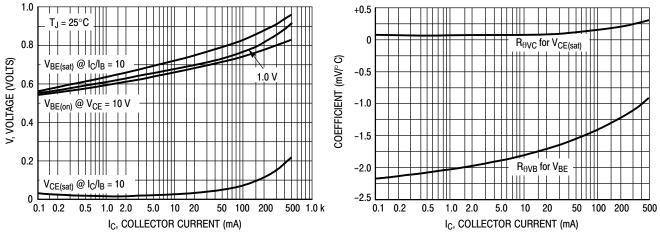
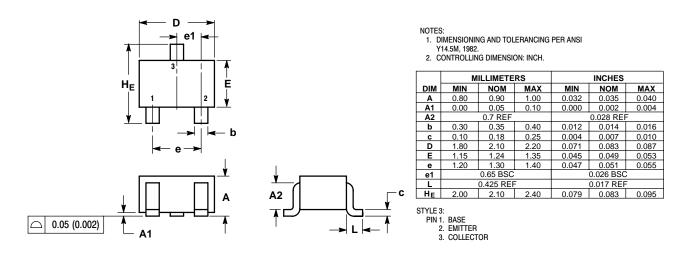


Figure 11. "On" Voltages

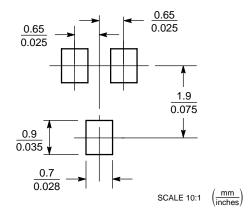
Figure 12. Temperature Coefficients

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE M



SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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